FDT434P

April 2011

FAIRCHILD

FDT434P

P-Channel 2.5V Specified PowerTrench[®] MOSFET

General Description

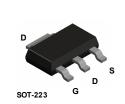
This P-Channel 2.5V specified MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

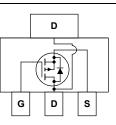
Applications

- Low Dropout Regulator
- DC/DC converter
- Load switch
- Motor driving

Features

- -5.5 A, -20 V. $R_{DS(ON)}$ = 0.050 Ω @ V_{GS} = -4.5 V $R_{DS(ON)}$ = 0.070 Ω @ V_{GS} = -2.5 V.
- Low gate charge (13nC typical)
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$.
- High power and current handling capability in a widely used surface mount package.





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-Source Voltage		-20	V	
V _{GSS}	Gate-Source Voltage		±8	V	
ID	Drain Current – Continuous	(Note 1a)	-6	A	
	– Pulsed		-30		
PD	Power Dissipation for Single Operation	(Note 1a)	3	W	
		(Note 1b)	1.3		
		(Note 1c)	1.1		
T _J , T _{stg}	Operating and Storage Junction Temperature Range		-55 to +150	°C	

Thermal Characteristics

R _{eJA}	Thermal Resistance, Junction-to-Ambient	(Note 1a)	42	°C/W			
R _{θJC}	Thermal Resistance, Junction-to-Case	(Note 1)	12	°C/W			

Package Marking and Ordering Information

-	evice Reel S	Size Tape width	Quantity
434 FD	T434P 13'	' 12mm	2500 units

Electrical Characteristics $T_{A} = 25^{\circ}C$ unless otherwise noted Symbol Min Parameter **Test Conditions** Тур Max Units **Off Characteristics** BV_{DSS} Drain-Source Breakdown Voltage -20 V $V_{GS} = 0 V, I_D = -250 \mu A$ Breakdown Voltage Temperature $I_D = -250 \,\mu\text{A}$, Referenced to 25°C -28 mV/°C ΔBV_{DSS} $\Delta T_{\rm J}$ Coefficient $V_{DS} = -16 V, V_{GS} = 0 V$ IDSS Zero Gate Voltage Drain Current -1 μA $V_{DS} = 0 V$ Gate-Body Leakage Current, V_{GS} = 8 V, 100 IGSSF nA Forward Gate-Body Leakage Current, $V_{GS} = -8 V$ $V_{DS} = 0 V$ -100 IGSSR nA Reverse **On Characteristics** (Note 2) Gate Threshold Voltage $V_{GS(th)}$ $V_{DS} = V_{GS}, I_D = -250 \overline{\mu A}$ -0.4 -0.6 -1 V Gate Threshold Voltage $I_D = -250 \ \mu A$, Referenced to $25^{\circ}C$ 2 mV/°C $\Delta V_{GS(th)}$ Temperature Coefficient ΔT_{J} Static Drain-Source $V_{GS} = -4.5 V_{,}$ $I_{D} = -6 A$ 0.040 0.050 R_{DS(on)} Ω $V_{GS} = -2.5 V$, $I_{D} = -4 A$ **On-Resistance** 0.050 0.070 V_{GS} = -4.5 V, I_D = -6 A T_J=125°C 0.067 0.083 V_{DS} = -5 V **On–State Drain Current** V_{GS} = -4.5 V, -20 А I_{D(on)} Forward Transconductance $V_{DS} = -10 V$, $I_{D} = -6 A$ 6.5 S **g**_{FS} **Dynamic Characteristics** $V_{GS} = 0 V$, Ciss Input Capacitance $V_{DS} = -10 V$, 1187 pF f = 1.0 MHz Coss **Output Capacitance** 270 pF **Reverse Transfer Capacitance** pF Crss 114 Switching Characteristics (Note 2) I_D = −1 A, Turn-On Delay Time $V_{DD} = -5 V$, 8 16 t_{d(on)} ns V_{GS} = -4.5 V, $R_{GEN} = 6 \Omega$ tr Turn–On Rise Time 15 25 ns t_{d(off)} Turn-Off Delay Time 45 65 ns tf Turn-Off Fall Time 30 50 ns Q_g Total Gate Charge $V_{DS} = -10 V$, $I_{\rm D} = -6 \, {\rm A},$ 13 19 nC $V_{GS} = -4.5 V$ Qas Gate-Source Charge nC 1.8 Q_{gd} Gate-Drain Charge 3 nC **Drain–Source Diode Characteristics and Maximum Ratings** Maximum Continuous Drain-Source Diode Forward Current -2.5 А I_{S} Drain-Source Diode Forward V_{SD} $V_{GS} = 0 V$, $I_S = -2.5 A$ (Note 2) -0.75 -1.2 V Voltage Notes: 1. R_{BLA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta,IC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. a) 42°C/W when b) 95°/W when mounted c) 110°/W when mounted on a mounted on a 1in² on a .0066 in² pad of minimum pad. pad of 2 oz copper 2 oz copper

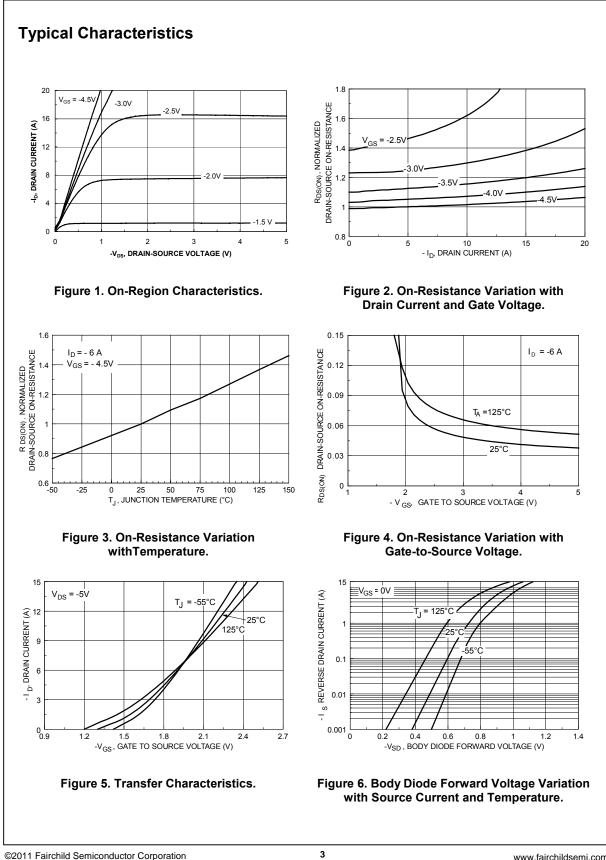
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Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%

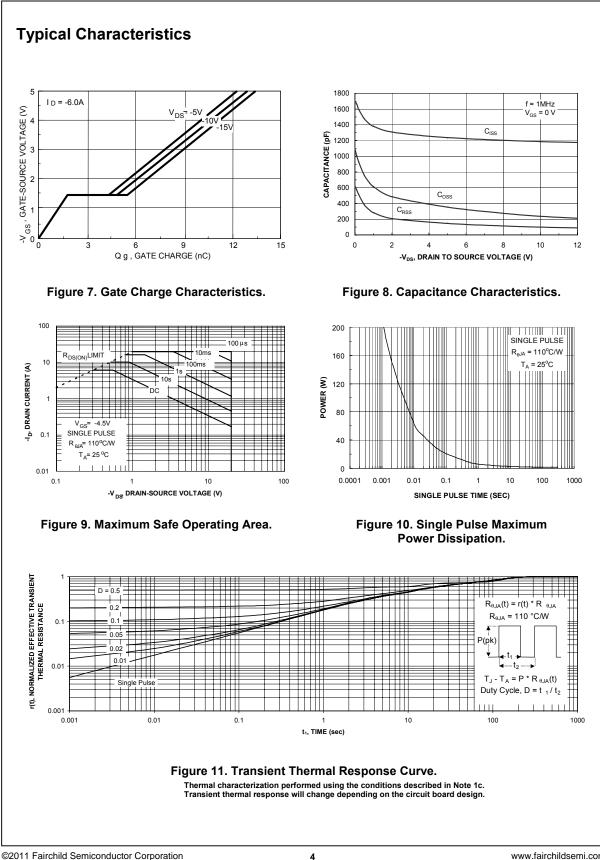
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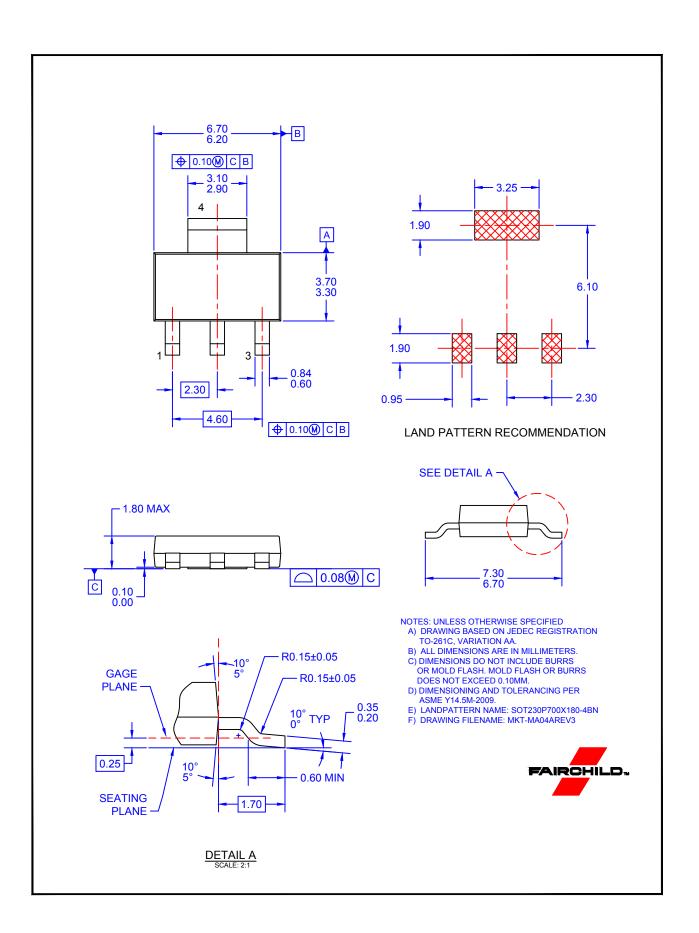
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